



**Power Rectifier**  
**Avalanche Diodes**  
**Type DA133-500-16**

High power cycling capability  
Low on-state and switching losses  
Optimized for line frequency rectifiers  
Designed for traction and industrial applications

Average forward current				$I_{FAV}$		500 A	
Repetitive peak reverse voltage				$V_{RRM}$		1000...1600 V	
$V_{RRM}, V$	1000	1100	1200	1300	1400	1500	1600
Voltage code	10	11	12	13	14	15	16
$T_j, ^\circ C$	-60...+150						

**MAXIMUM ALLOWABLE RATINGS**

Symbols and parameters		Units	Values	Test conditions	
<b>ON-STATE</b>					
$I_{FAV}$	Maximum allowable average forward current	A	500 788	$T_c=123\ ^\circ C$ ; Double side cooled; $T_c=100\ ^\circ C$ ; Double side cooled; 180° half-sine wave; 50 Hz	
$I_{FRMS}$	RMS forward current	A	785	$T_c=123\ ^\circ C$ ; Double side cooled; 180° half-sine wave; 50 Hz	
$I_{FSM}$	Surge forward current	kA	12.0 14.0	$T_j=T_{j\ max}$ $T_j=25\ ^\circ C$	180° half-sine wave; $t_p=10\ ms$ ; single pulse; $V_R=0\ V$ ;
			13.0 15.0	$T_j=T_{j\ max}$ $T_j=25\ ^\circ C$	180° half-sine wave; $t_p=8.3\ ms$ ; single pulse; $V_R=0\ V$ ;
$I^2t$	Safety factor	$A^2s \cdot 10^3$	720 980	$T_j=T_{j\ max}$ $T_j=25\ ^\circ C$	180° half-sine wave; $t_p=10\ ms$ ; single pulse; $V_R=0\ V$ ;
			700 930	$T_j=T_{j\ max}$ $T_j=25\ ^\circ C$	180° half-sine wave; $t_p=8.3\ ms$ ; single pulse; $V_R=0\ V$ ;
<b>BLOCKING</b>					
$V_{RRM}$	Repetitive peak reverse voltages	V	1000...1600	$T_{j\ min} < T_j < T_{j\ max}$ ; 180° half-sine wave; 50 Hz;	
$V_{(BR)}$	Breakdown voltage	V	1250...2000	$T_j=25\ ^\circ C$ ; $I_{br}=100\ mA$ ; $t_p = 10\ ms$ ; 5 Hz	
$V_R$	Reverse continuous voltages	V	$0.6 \cdot V_{RRM}$	$T_j=T_{j\ max}$ ;	
$P_{RSM}$	Surge reverse power dissipation	kW	16	$T_j= T_{j\ max}$ ; $t_p=100\ \mu s$ ; 180° half-sine current waveforms; single pulse	
<b>THERMAL</b>					
$T_{stg}$	Storage temperature	$^\circ C$	-60...+50		
$T_j$	Operating junction temperature	$^\circ C$	-60...+150		
<b>MECHANICAL</b>					
F	Mounting force	kN	9.0...11.0		
a	Acceleration	$m/s^2$	50	Device clamped	

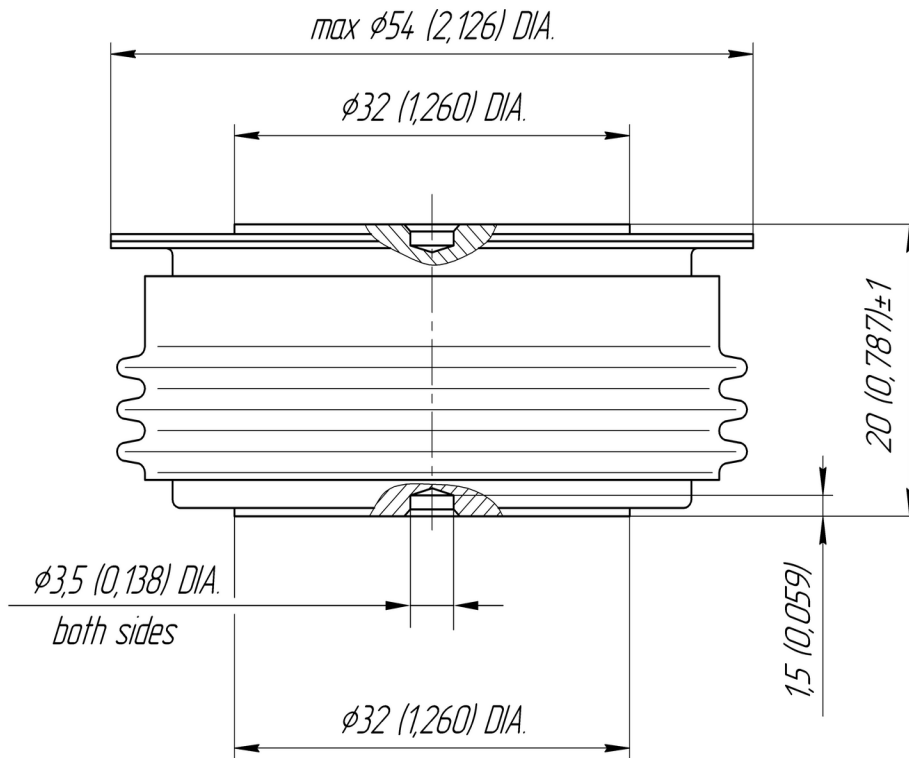
## CHARACTERISTICS

Symbols and parameters		Units	Values	Conditions
<b>ON-STATE</b>				
$V_{FM}$	Peak forward voltage, max	V	1.50	$T_j=25\text{ }^\circ\text{C}; I_{FM}=1570\text{ A}$
$V_{F(TO)}$	Forward threshold voltage, max	V	0.878	$T_j=T_{j\text{ max}};$
$r_T$	Forward slope resistance, max	m $\Omega$	0.366	$0.5\pi I_{FAV} < I_T < 1.5\pi I_{FAV}$
<b>BLOCKING</b>				
$I_{RRM}$	Repetitive peak reverse current, max	mA	25	$T_j=T_{j\text{ max}};$ $V_R=V_{RRM}$
<b>SWITCHING</b>				
$Q_{rr}$	Total recovered charge, max	$\mu\text{C}$	1650	$T_j=T_{j\text{ max}}; I_{FM}=I_{FAV};$
$t_{rr}$	Reverse recovery time, max	$\mu\text{s}$	24	$di_R/dt=-10\text{ A}/\mu\text{s};$
$I_{rr}$	Reverse recovery current, max	A	137	$V_R=100\text{ V}$
<b>THERMAL</b>				
$R_{thjc}$	Thermal resistance, junction to case, max	$^\circ\text{C}/\text{W}$	0.040	Double side cooled
$R_{thjc-A}$			0.088	Anode side cooled
$R_{thjc-K}$			0.072	Cathode side cooled
$R_{thck}$	Thermal resistance, case to heatsink, max	$^\circ\text{C}/\text{W}$	0.008	Direct current
<b>MECHANICAL</b>				
m	Weight, max	g	180	
$D_s$	Surface creepage distance	mm (inch)	23.69 (0.933)	
$D_a$	Air strike distance	mm (inch)	19.10 (0.752)	

### PART NUMBERING GUIDE

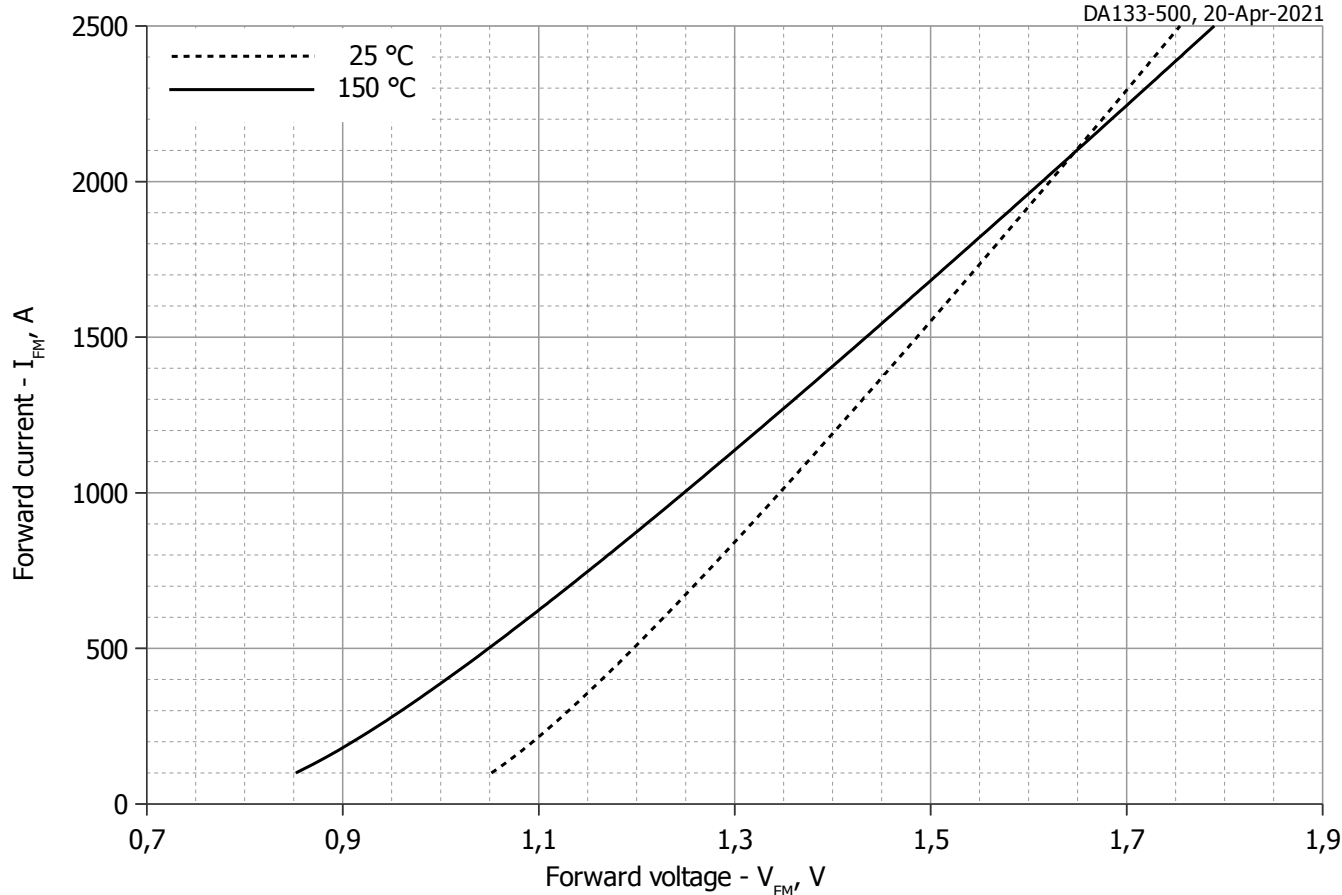
DA	133	500	16	N
1	2	3	4	5

1. DA — Avalanche Diode
2. Design version
3. Average forward current, A
4. Voltage code
5. Ambient conditions: N – normal; T – tropical



All dimensions in millimeters (inches)

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In the interest of product improvement, Proton-Electrotex reserves the right to change data sheet without notice.



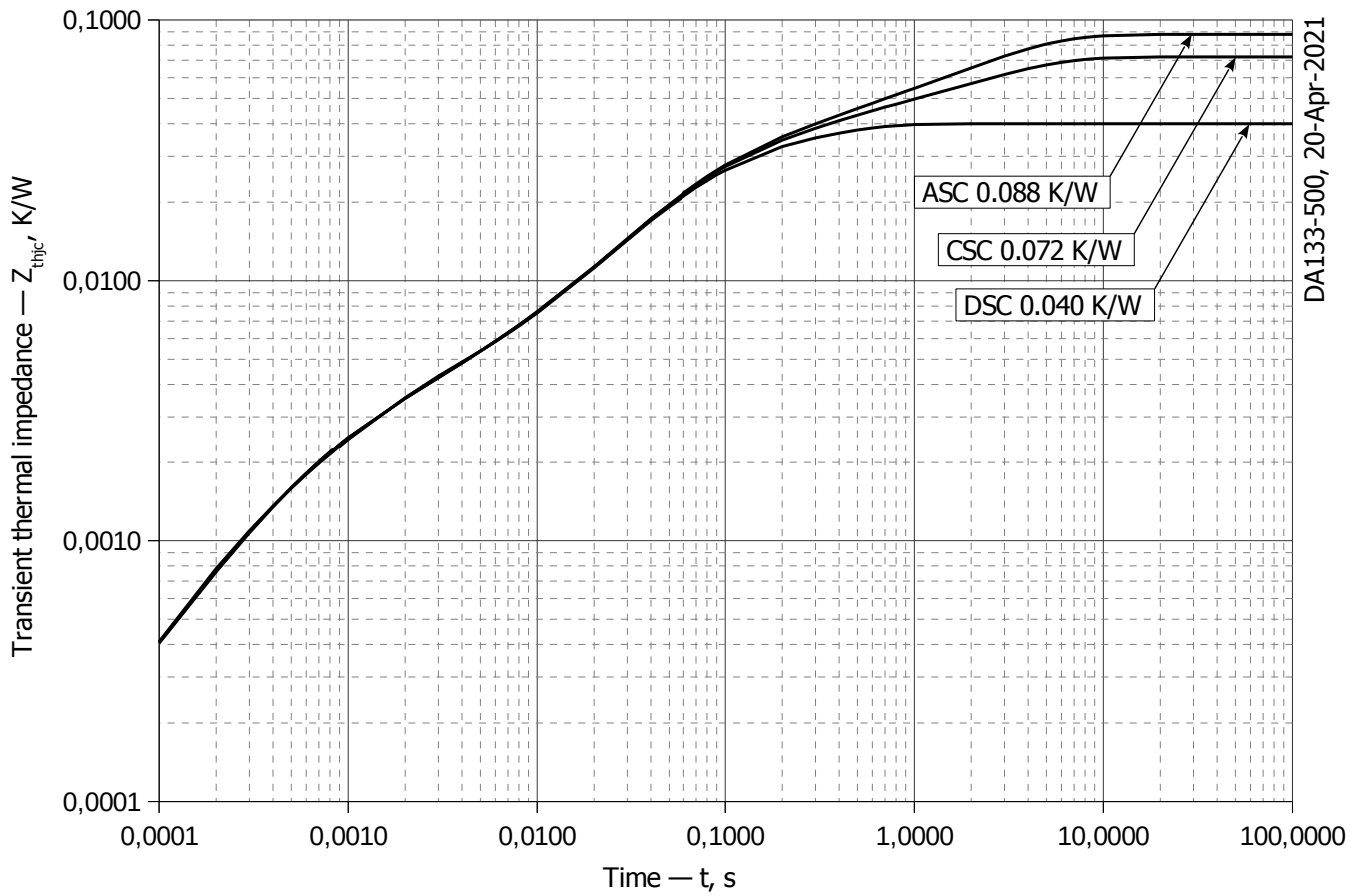
**Fig 1 – Forward characteristics of Limit device**

Analytical function for Forward characteristic:

$$V_F = A + B \cdot i_F + C \cdot \ln(i_F + 1) + D \cdot \sqrt{i_F}$$

	Coefficients for max curves	
	$T_j = 25^\circ\text{C}$	$T_j = T_{j\text{max}}$
<b>A</b>	0.95219630	0.70586859
<b>B</b>	0.00023001	0.00030143
<b>C</b>	0.01018891	0.01643547
<b>D</b>	0.00295230	0.00402775

**Forward characteristic model (see Fig. 1).**



**Fig 2 – Transient thermal impedance  $Z_{thjc}$  vs. time  $t$**

Analytical function for Transient thermal impedance junction to case  $Z_{thjc}$  for DC:

$$Z_{thjc} = \sum_{i=1}^n R_i \left( 1 - e^{-\frac{t}{\tau_i}} \right)$$

Where  $i = 1$  to  $n$ ,  $n$  is the number of terms in the series.

$t$  = Duration of heating pulse in seconds.

$Z_{thjc}$  = Thermal resistance at time  $t$ .

$R_i$  = Amplitude of  $p_{th}$  term.

$\tau_i$  = Time constant of  $r_{th}$  term.

DC Double side cooled

$i$	1	2	3	4	5	6
$R_i, K/W$	0.01423	0.01906	0.003576	0.002535	-4.666e-005	0.0006479
$\tau_i, s$	0.265	0.05901	0.03499	0.001252	0.000001	0.0002488

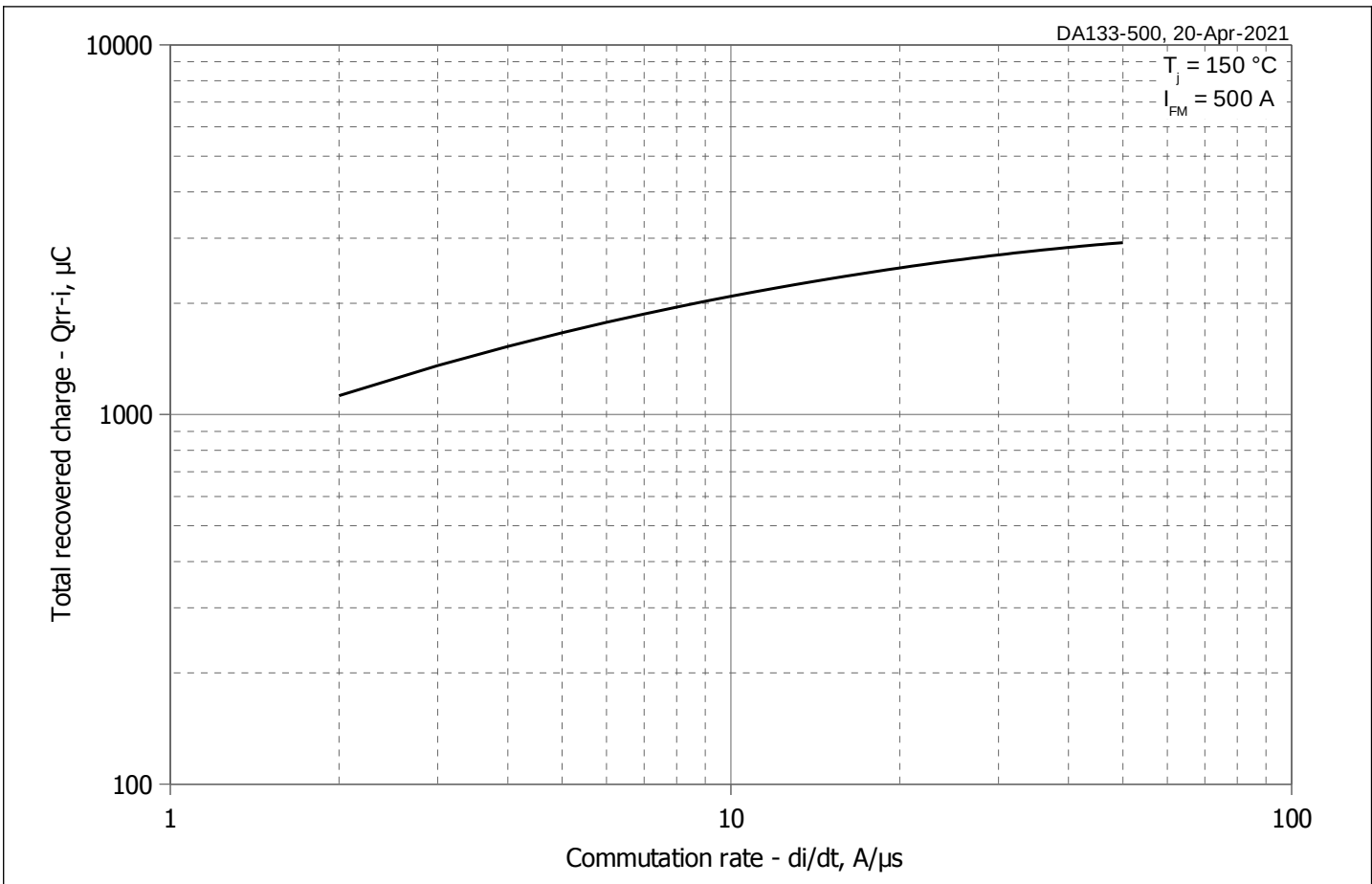
DC Anode side cooled

$i$	1	2	3	4	5	6
$R_i, K/W$	0.04804	0.001789	0.01342	0.02147	0.001374	0.001945
$\tau_i, s$	2.651	0.4195	0.2622	0.05451	0.002585	0.0005847

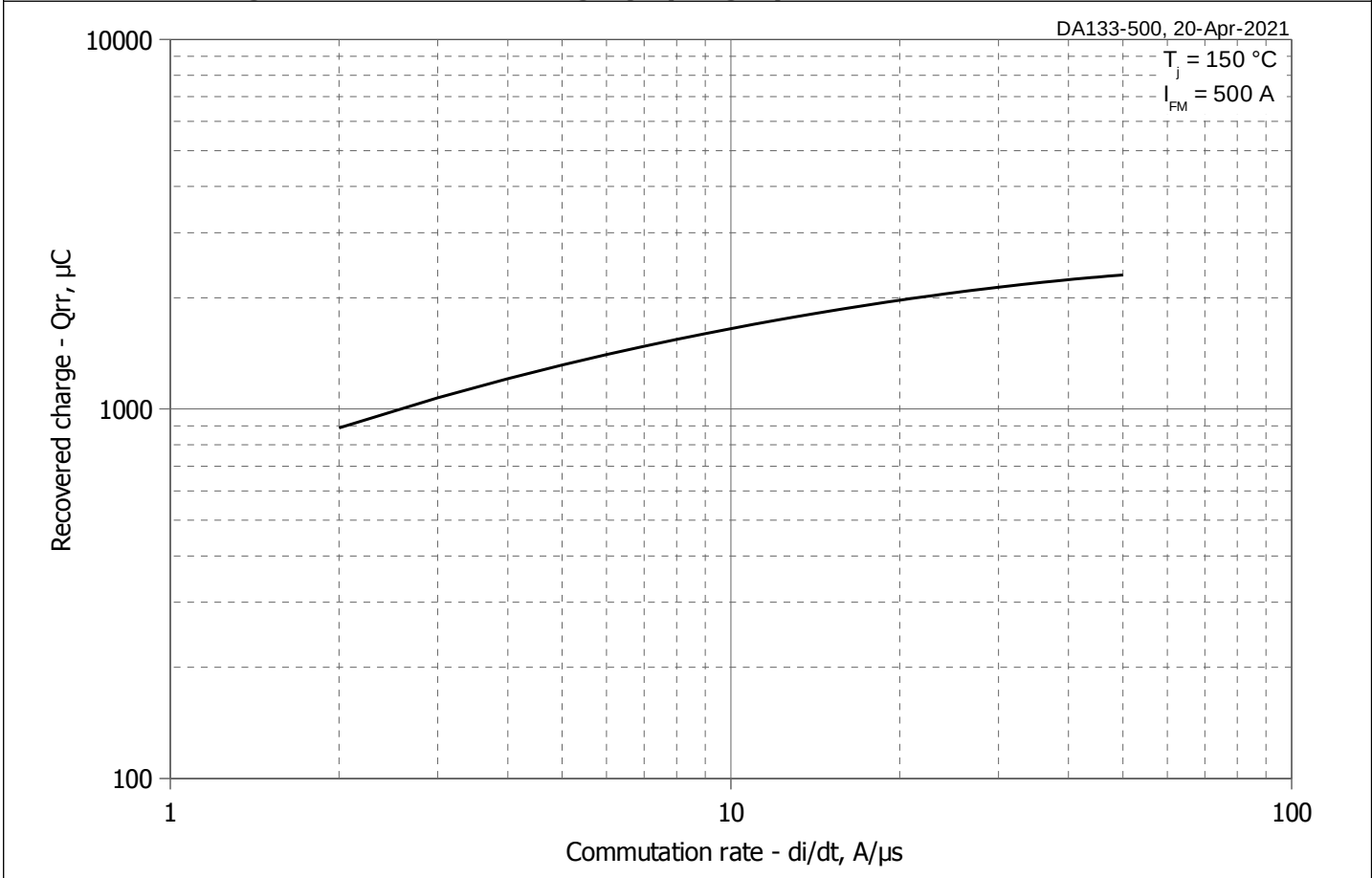
DC Cathode side cooled

$i$	1	2	3	4	5	6
$R_i, K/W$	0.03216	0.01306	0.002934	0.02064	0.001493	0.001786
$\tau_i, s$	2.647	0.2831	0.1455	0.05284	0.002255	0.0005519

**Transient thermal impedance junction to case  $Z_{thjc}$  model (see Fig. 2)**

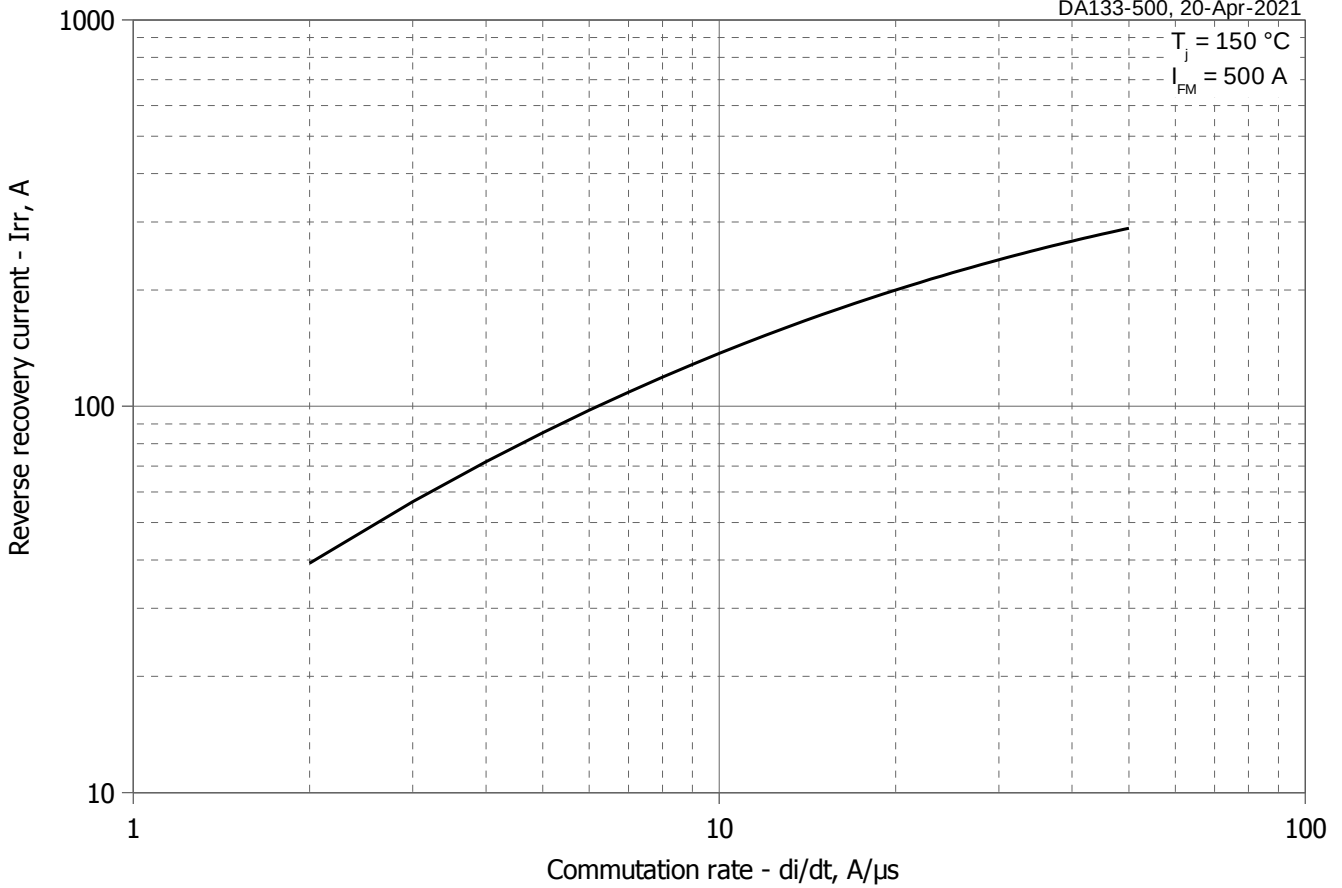


**Fig 3 - Total recovered charge  $Q_{rr-i}$  (integral) vs. commutation rate  $di_R/dt$**



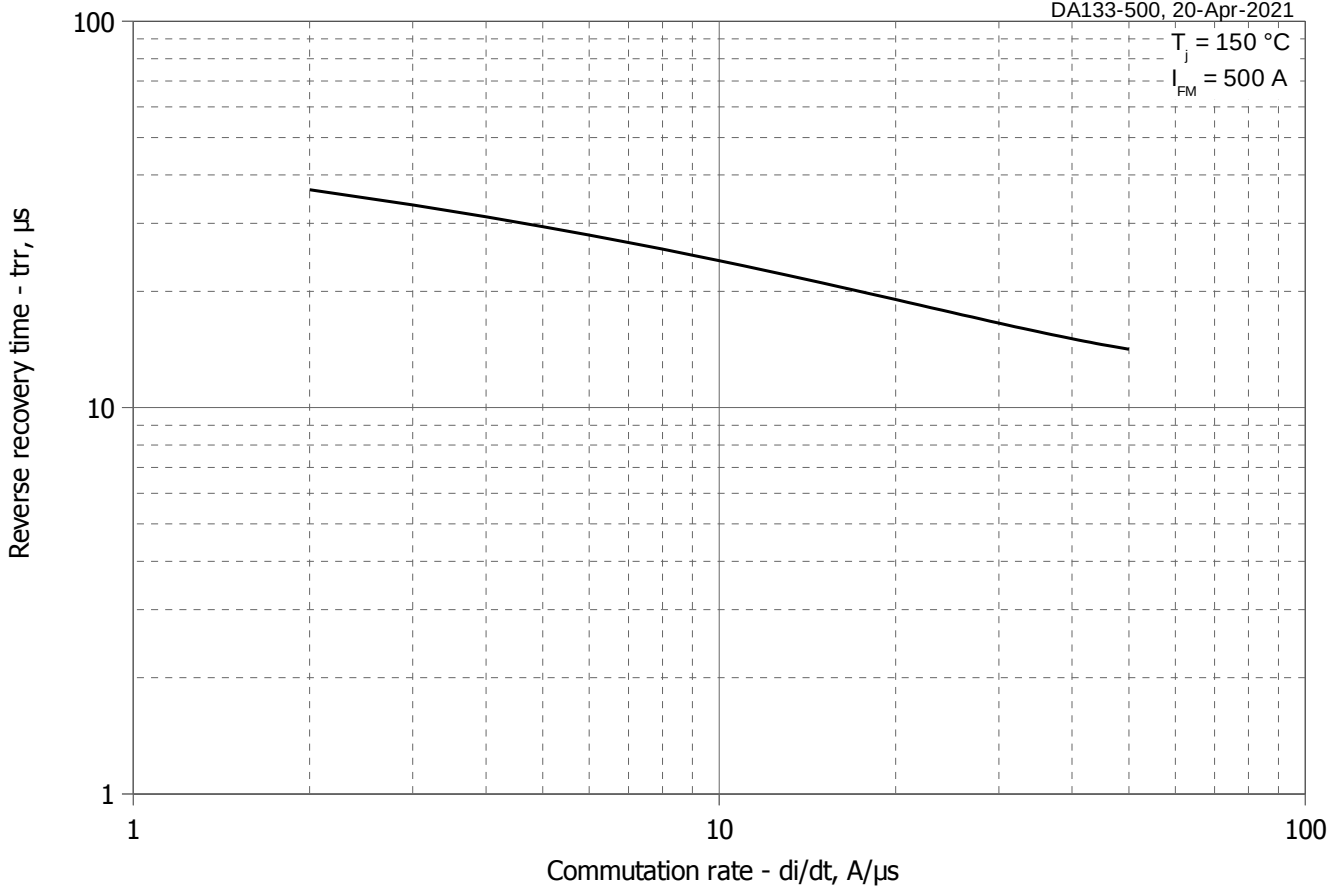
**Fig 4 - Maximum recovered charge  $Q_{rr}$  vs. commutation rate  $di_R/dt$  (25% chord)**

$T_j = 150\text{ }^\circ\text{C}$   
 $I_{FM} = 500\text{ A}$

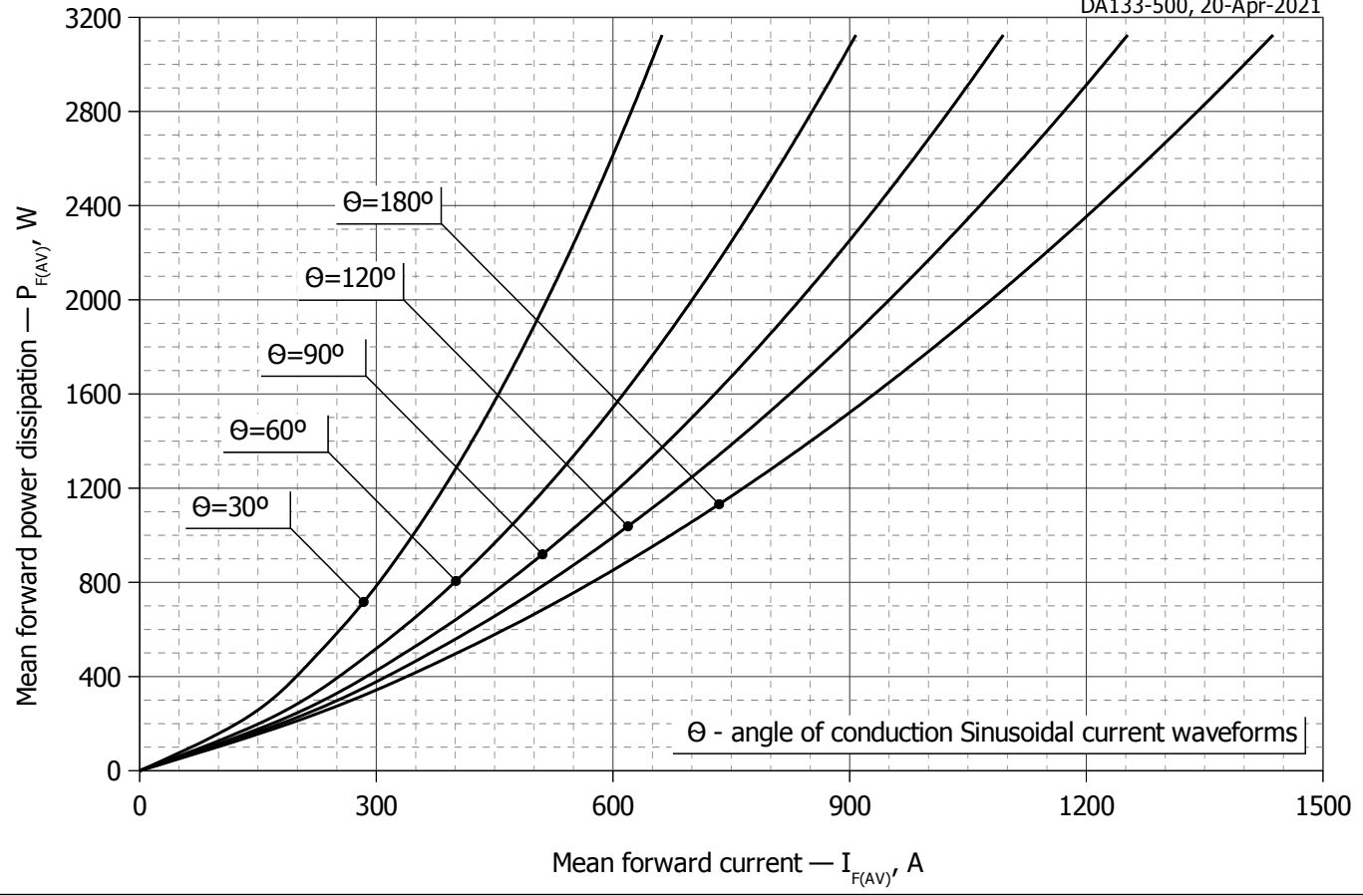


**Fig 5 - Maximum reverse recovery current  $I_{rr}$  vs. commutation rate  $di_R/dt$**

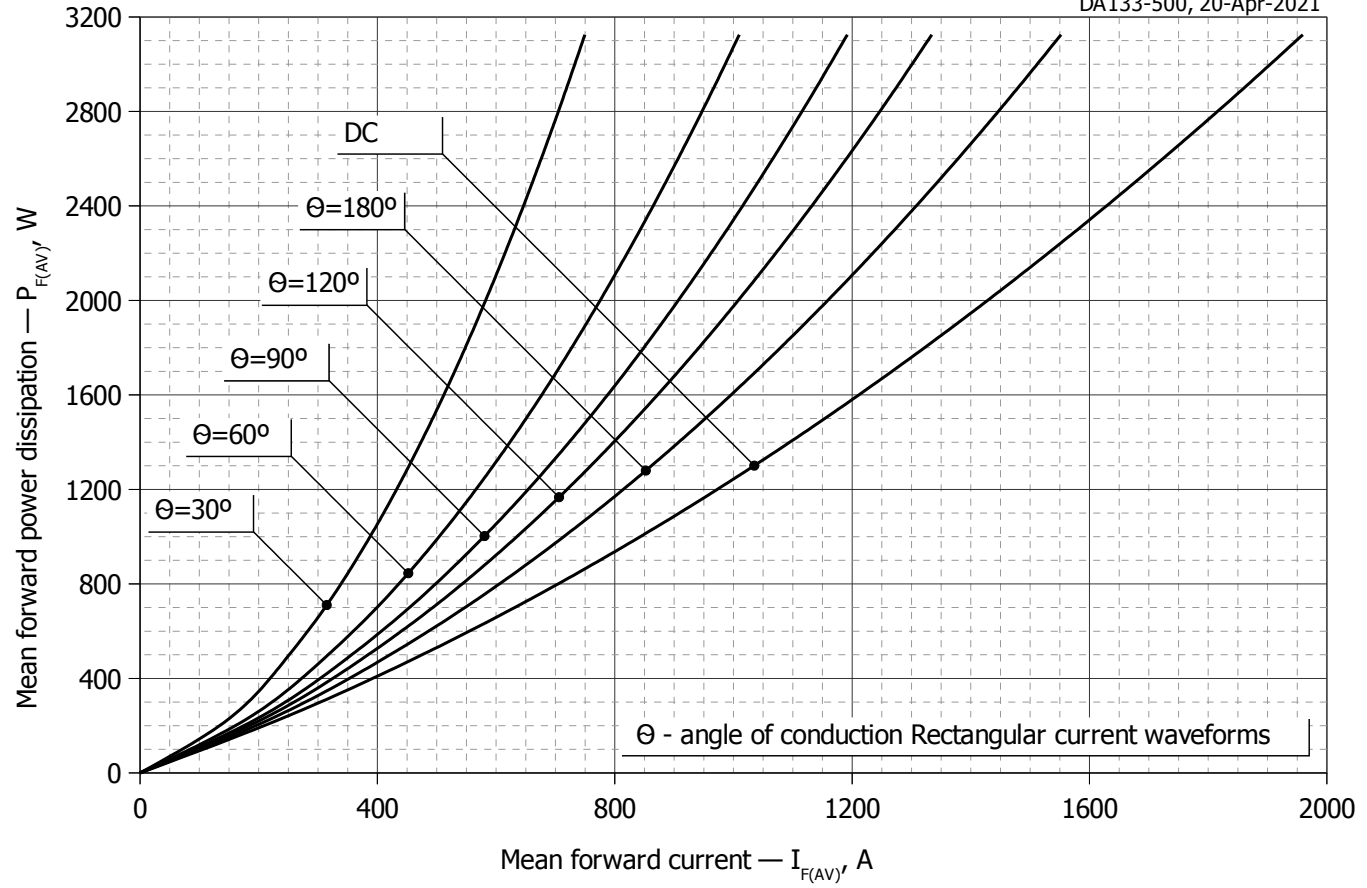
$T_j = 150\text{ }^\circ\text{C}$   
 $I_{FM} = 500\text{ A}$



**Fig 6 - Maximum recovery time  $t_{rr}$  vs. commutation rate  $di_R/dt$  (25% chord)**

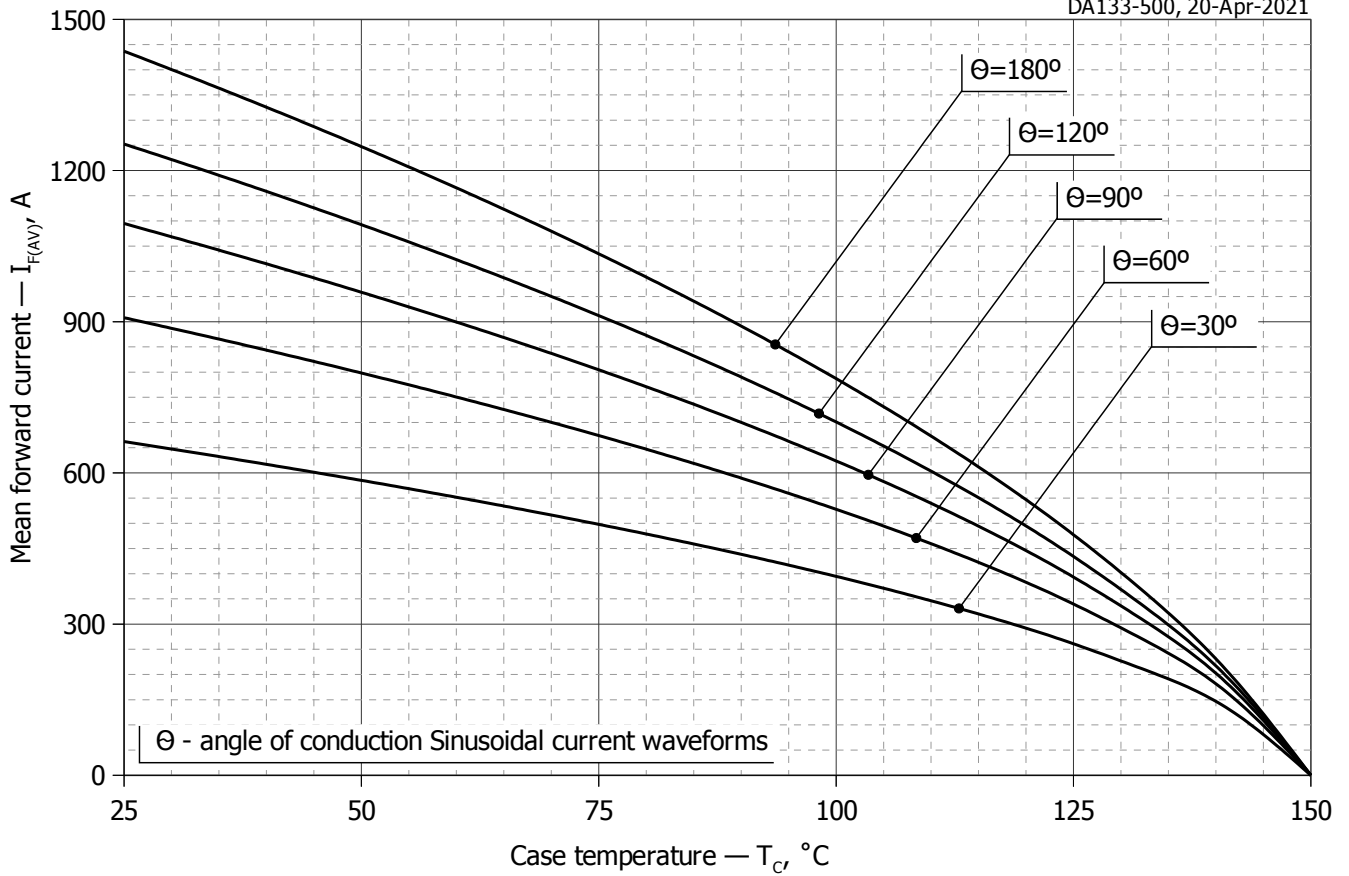


**Fig. 7 - Mean forward power dissipation  $P_{FAV}$  vs. mean forward current  $I_{FAV}$  for sinusoidal current waveforms at different conduction angles (f=50Hz, DSC)**

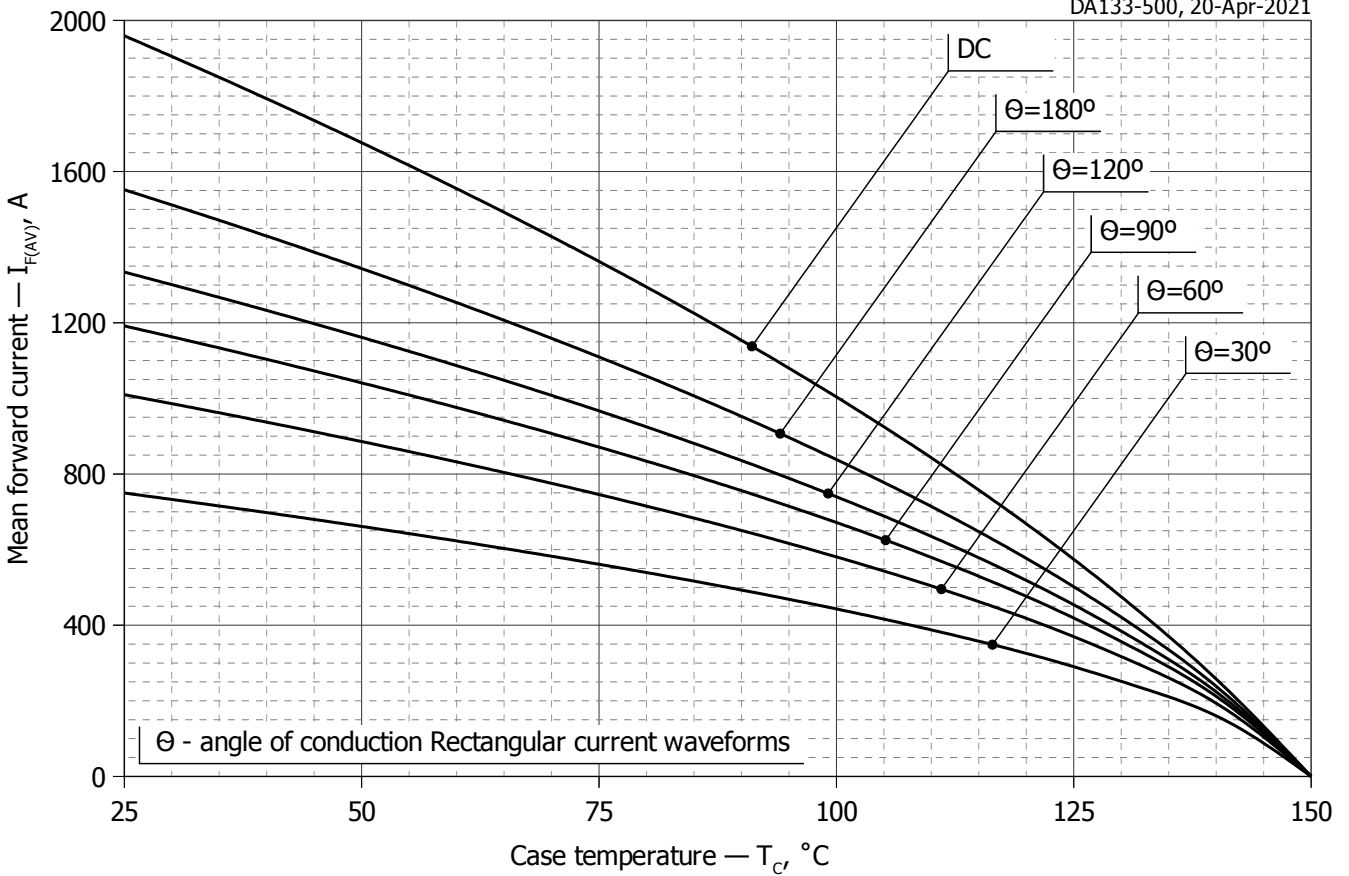


**Fig. 8 - Mean forward power dissipation  $P_{FAV}$  vs. mean forward current  $I_{FAV}$  for rectangular current waveforms at different conduction angles and for DC (f=50Hz, DSC)**

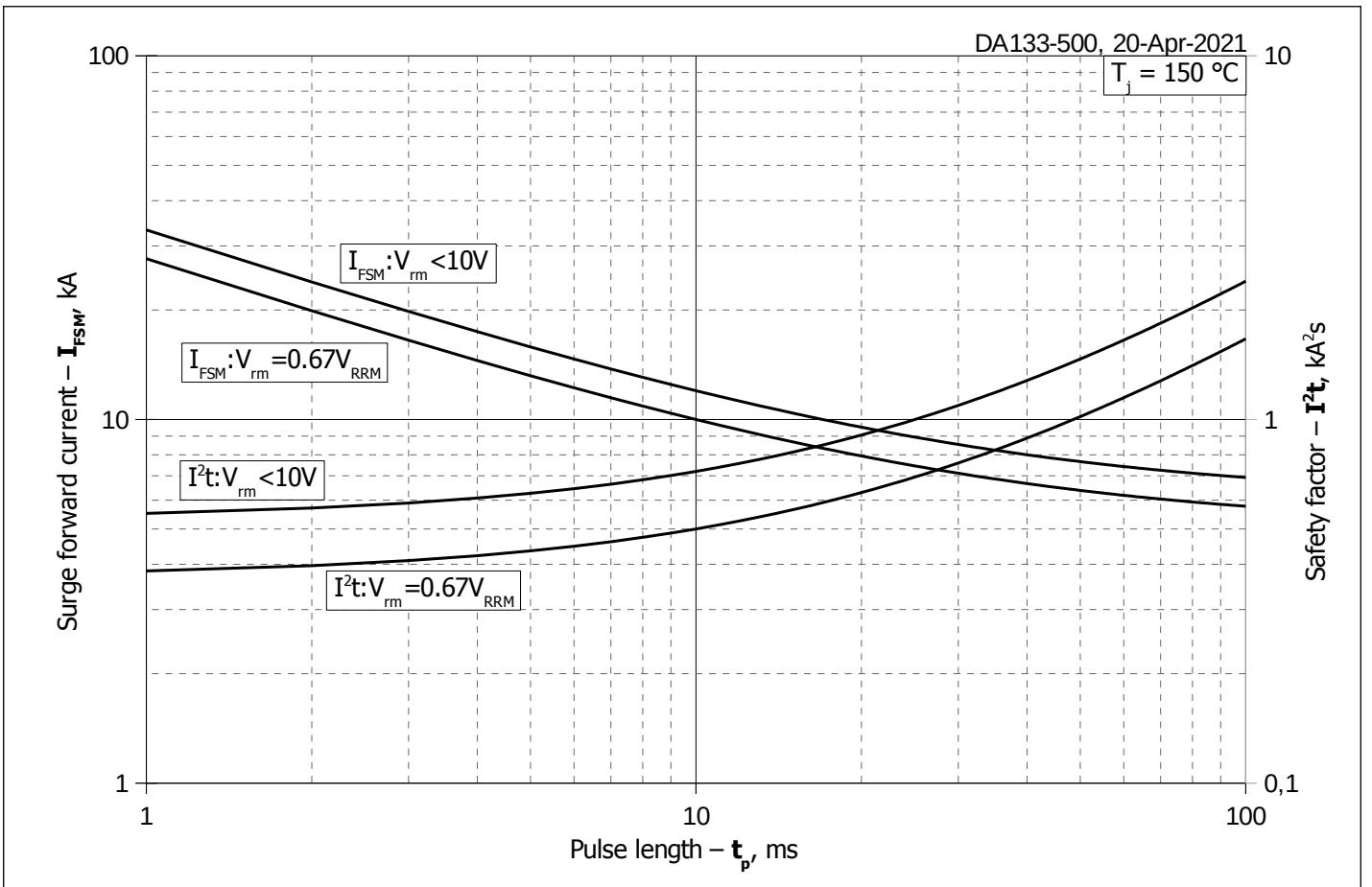




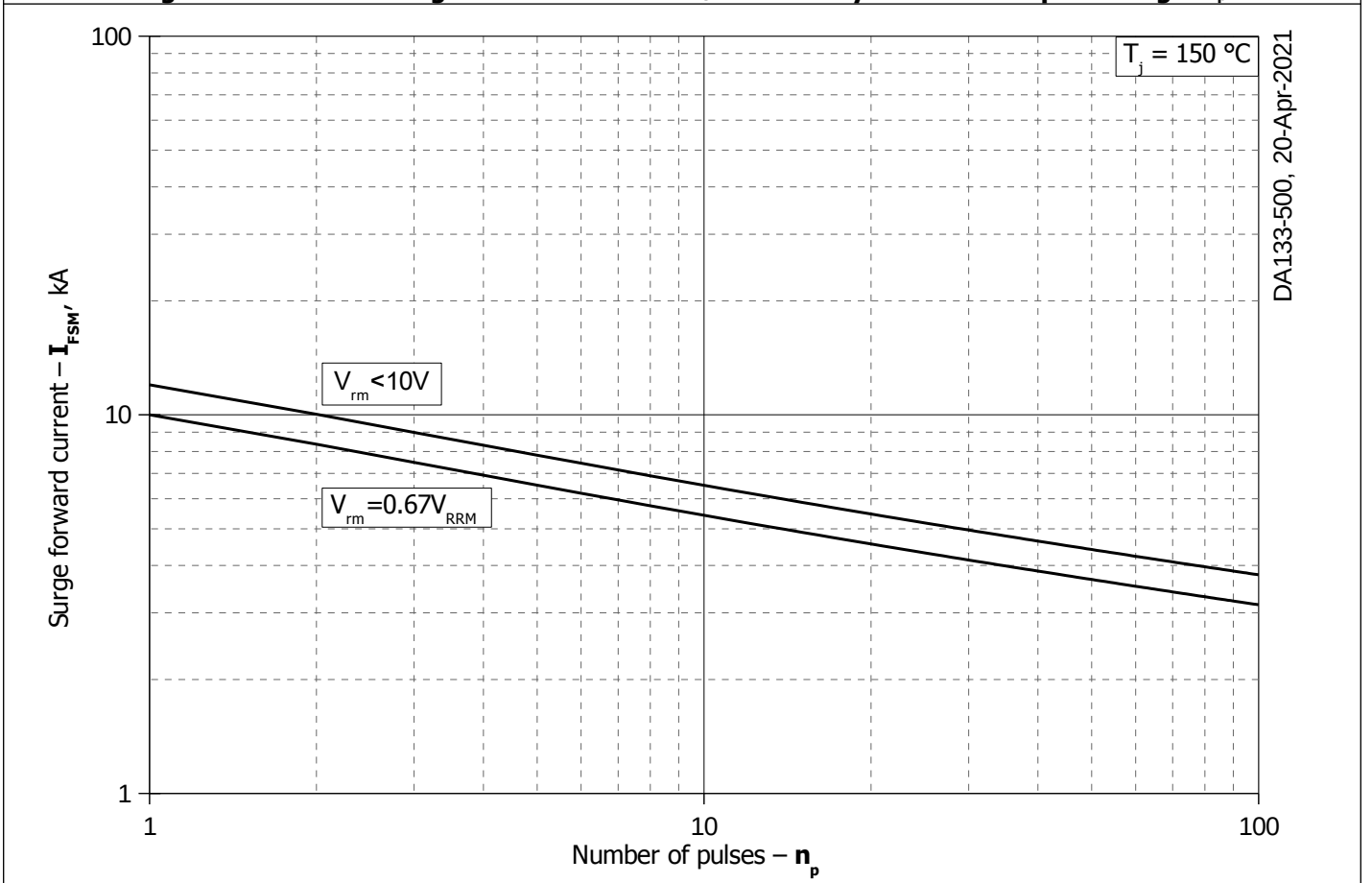
**Fig. 9 – Mean forward current  $I_{FAV}$  vs. case temperature  $T_C$  for sinusoidal current waveforms at different conduction angles (f=50Hz, DSC)**



**Fig. 10 - Mean forward current  $I_{FAV}$  vs. case temperature  $T_C$  for rectangular current waveforms at different conduction angles and for DC (f=50Hz, DSC)**



**Fig. 11 – Maximum surge forward current  $I_{FSM}$  and safety factor  $I^2t$  vs. pulse length  $t_p$**



**Fig. 12 - Maximum surge forward current  $I_{FSM}$  vs. number of pulses  $n_p$**